

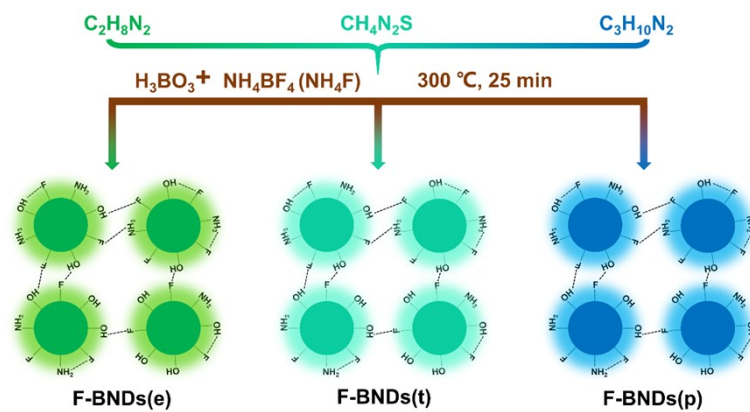
## Electronic Supplementary Information

### **Long-lived fluorinated boron-nitride dots exhibiting room-temperature phosphorescence and high-temperature resistance**

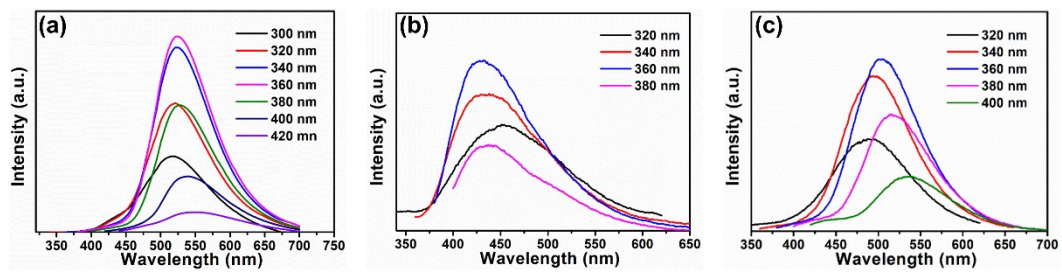
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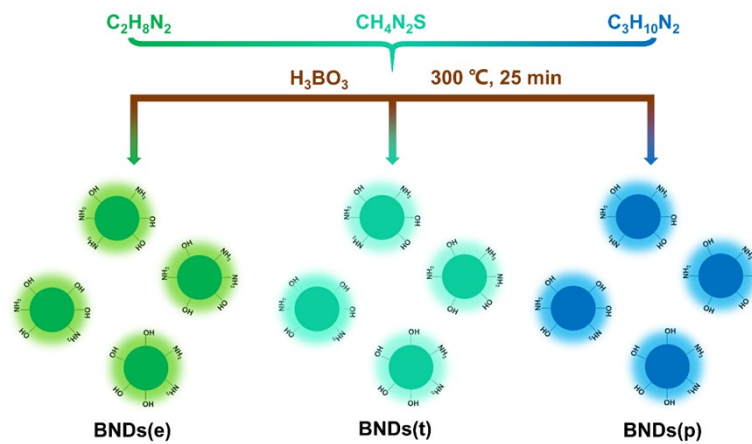
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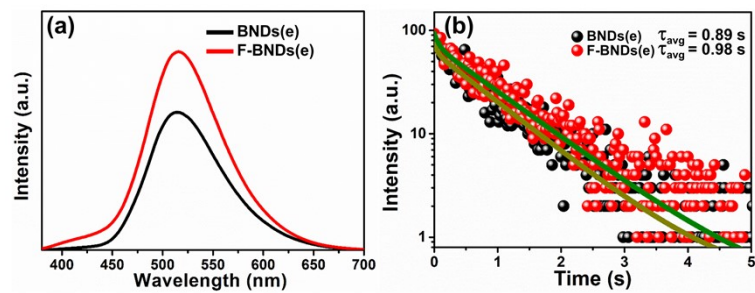
**Fig. S1** Synthetic procedures of F-BNDs(e), F-BNDs(t) and F-BNDs(p).



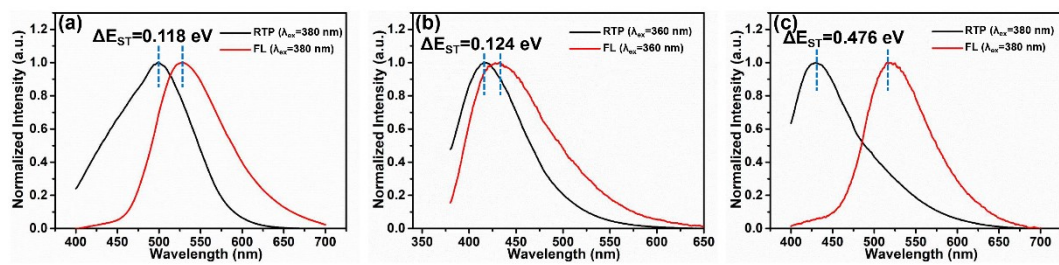
**Fig. S2** The phosphorescence emission spectra excited at different wavelengths of (a) F-BNDs(e), (b) F-BNDs(p) and (c) F-BNDs(t).



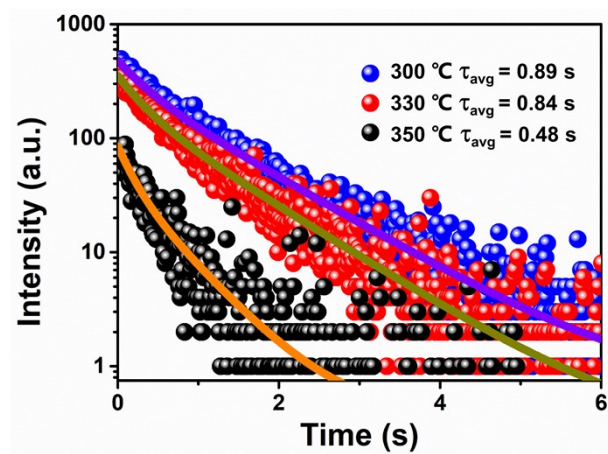
**Fig. S3** Synthetic procedures of BNDs(e), BNDs(t) and BNDs(p).



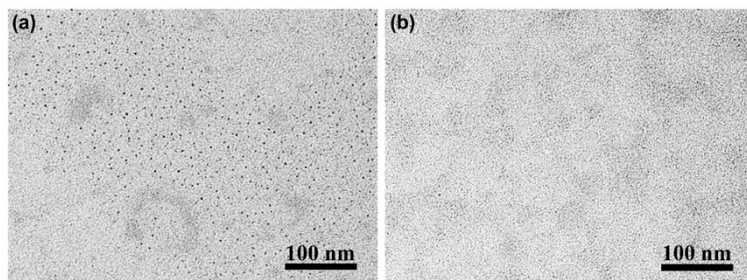
**Fig. S4** (a) The phosphorescence emission spectra of F-BNDs(e) and BNDs(e) under 360 nm excitation. (b) Time-resolved phosphorescence decay curves of F-BNDs(e) and BNDs(e) under 360 nm excitation.



**Fig. S5** FL and phosphorescence spectra excited at 360 nm of (a) F-BNDs(e), (b) F-BNDs(p) and (c) F-BNDs(t).

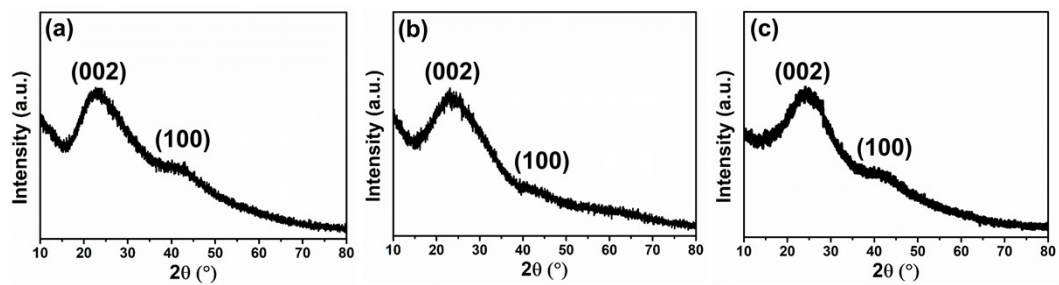


**Fig. S6** Time-resolved phosphorescence decay curves of BNDs(e) obtained at 300, 330 and 350 °C.

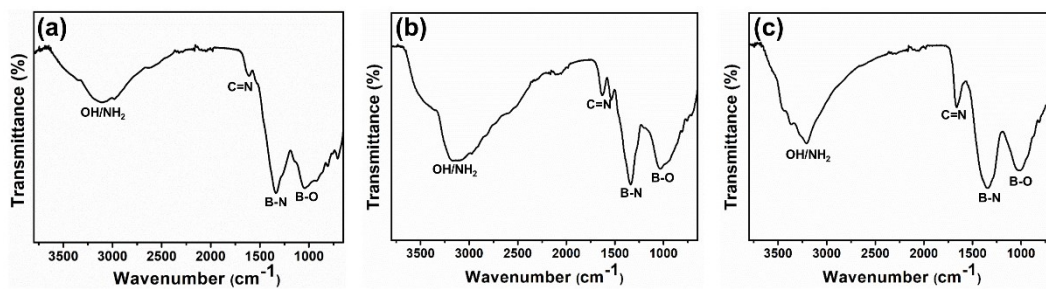


**Fig. S7** TEM images of (a) F-BNDs(p) and (b) F-BNDs(t).

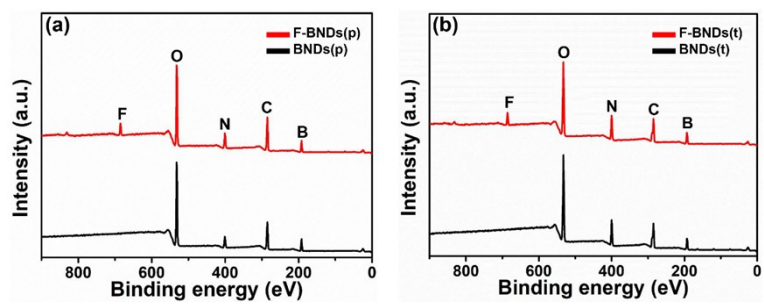




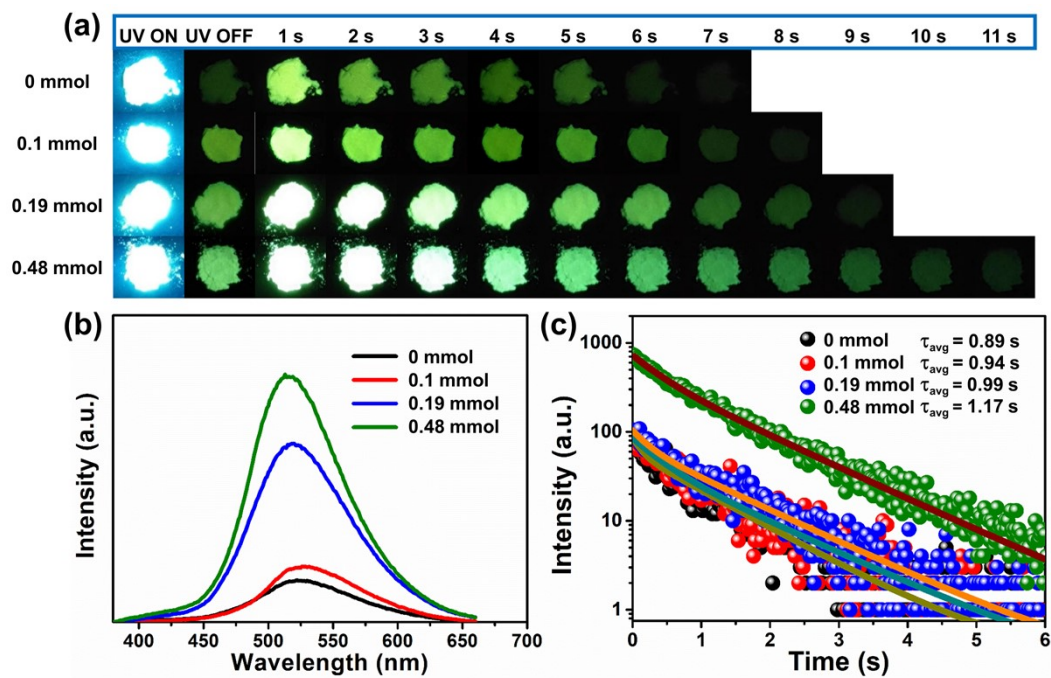
**Fig. S8** XRD patterns of (a) F-BNDs(e), (b) F-BNDs(p) and (c) F-BNDs(t).



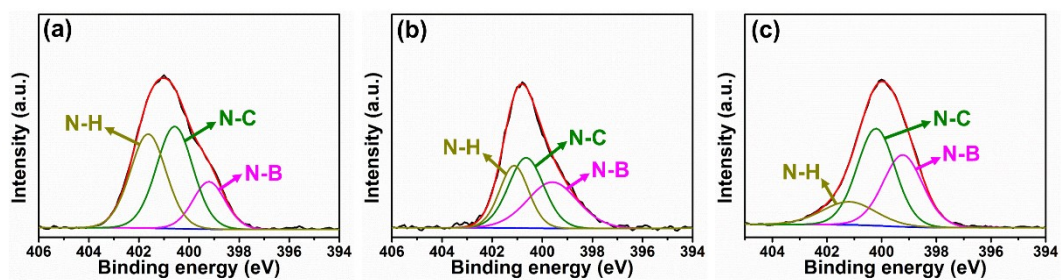
**Fig. S9** FTIR spectra of (a) F-BNDs(e), (b) F-BNDs(p) and (c) F-BNDs(t).



**Fig. S10** (a) The survey XPS spectra of F-BNDs(p) and BNDs(p). (b) The survey XPS spectra of F-BNDs(t) and BNDs(t).

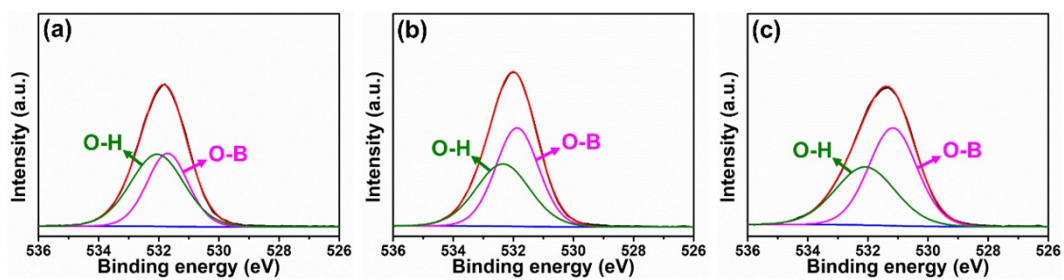


**Fig. S11** (a) The photographs of F-BNDs(e) with different fluorine contents taken after the stoppage of 405 nm excitation. (b) The RTP spectra under 360 nm excitation and (c) time-resolved phosphorescence decay curves of F-BNDs(e) with different fluorine contents



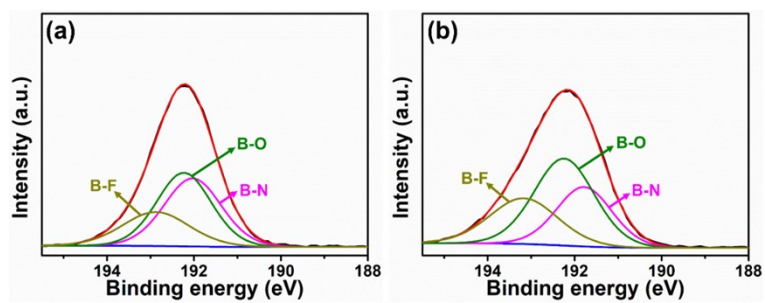
**Fig. S12** High-resolution N1s spectra of (a) F-BNDs(e), (b) F-BNDs(p) and (c) F-BNDs(t).

High-resolution spectrum of N 1s bands demonstrates three peaks in 399.2, 400.6 and 401.6 eV, which are attributed to N-B, N-C/N-O and N-H bonds,<sup>1, 2</sup> respectively. The N-H bond implies the presence of -NH<sub>2</sub> groups.

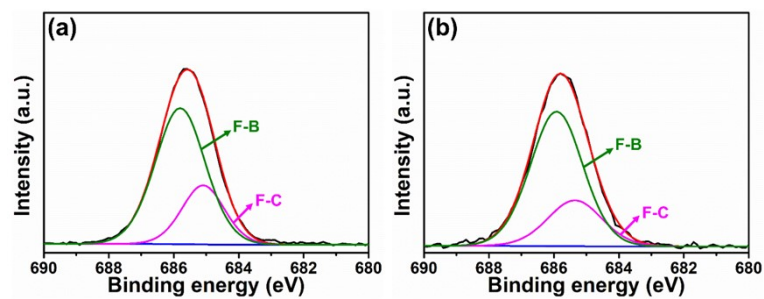


**Fig. S13** High-resolution O1s spectra of (a) F-BNDs(e), (b) F-BNDs(p) and (c) F-BNDs(t).

The high-resolution O1s spectra exhibit two peaks, including O-B at 531.7 and O-H at 532.1 eV.<sup>3</sup>



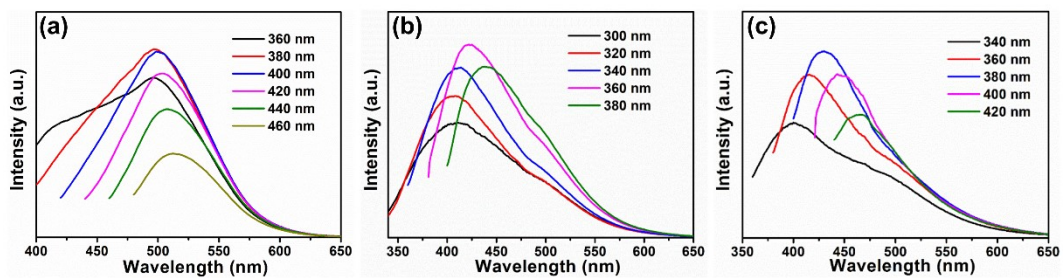
**Fig. S14** High-resolution B1s spectra of (a) F-BNDs(p) and (b) F-BNDs(t).



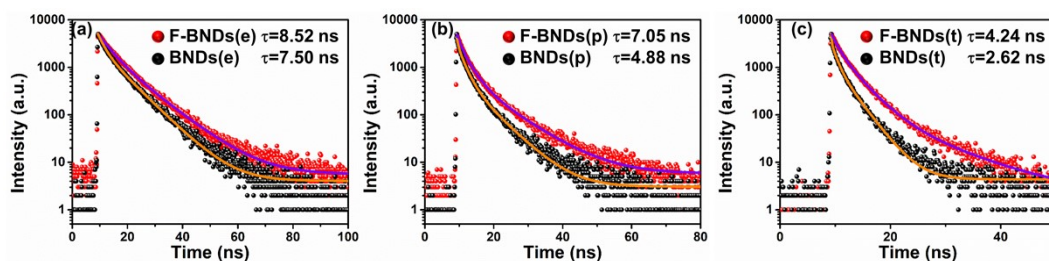
**Fig. S15** High-resolution F1s spectra of (a) F-BNDs(p) and (b) F-BNDs(t).

The high-resolution spectrum of F1s shows two peaks at 684.9 and 685.6 eV for F-C and F-B bonds,<sup>4,5</sup> respectively.



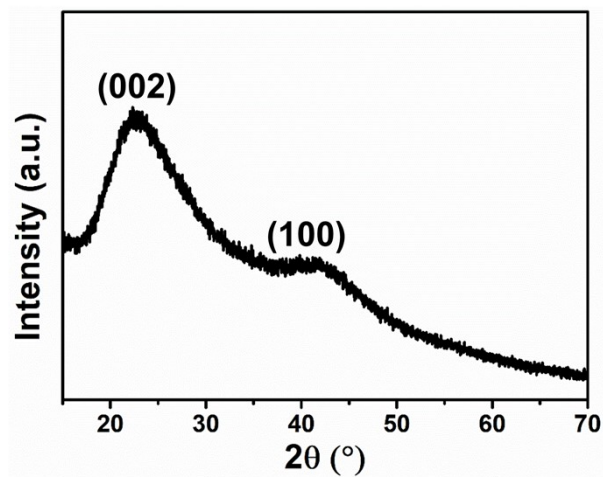


**Fig. S16** FL emission spectra excited at different wavelengths of (a) F-BNDs(e), (b) F-BNDs(p) and (c) F-BNDs(t).



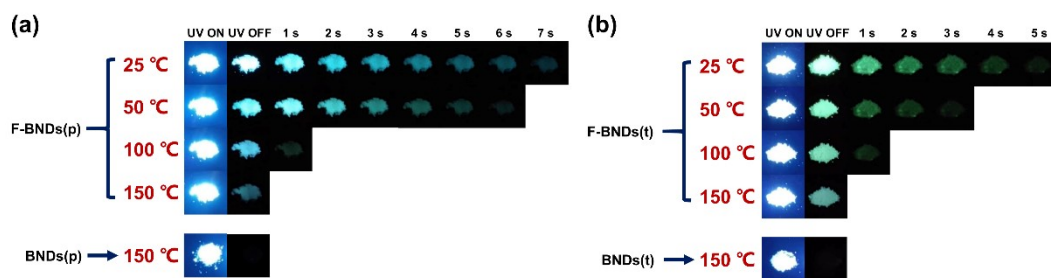
**Fig. S17** (a) Time-resolved FL decay curves of F-BNDs(e) and BNDs(e) under 380 nm excitation. (b) Time-resolved FL decay curves of F-BNDs(p) and BNDs(p) under 380 nm excitation. (c) Time-resolved FL decay curves of F-BNDs(t) and BNDs(t) under 340 nm excitation.

The FL decay spectra of three F-BNDs are fitted to give FL lifetimes of 8.52, 7.05, and 4.24 ns for F-BNDs(e), F-BNDs(p) and F-BNDs(t), respectively. It is worth noting that the FL lifetimes of BNDs(e), BNDs(t) and BNDs(p) are 7.50, 4.88 and 2.62 ns, which are shorter than corresponding F-BNDs, respectively. These results should be attributed to the effect of hydrogen-bond network, suppressing the non-radiative transitions. Higher  $-NH_2$  and  $-OH$  ratios are conducive to the formation of stronger inter- and intra-dot hydrogen-bond networks, exhibiting the longer FL and RTP lifetime.

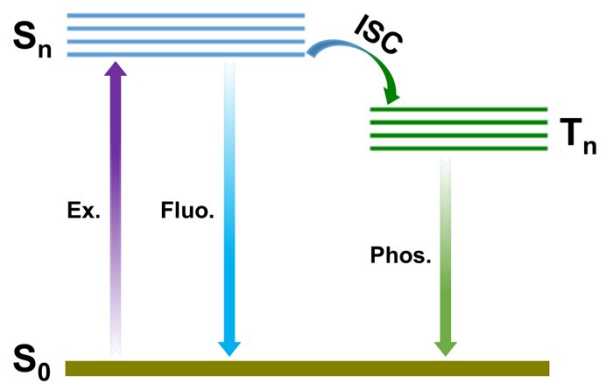


**Fig. S18** The XRD pattern of the F-BNDs(e) after treatment at 700 °C for 0.5 h in air condition.

The F-BNDs(e) were treated at 700 °C for 0.5 h in air condition. After that, most of the sample was maintained and the phase composition is consistent with that before heating, exhibiting excellent thermal stability.



**Fig. S19** The photographs of (a) F-BNDs(p) and (b) F-BNDs(t) taken after the stoppage of 405 nm excitation by varying temperatures from 25 to 150 °C and photographs of corresponding BNDs taken at 150 °C.



**Fig. S20** Schematic illustration of the RTP emission mechanisms of the F-BNDs.

**Tab. S1** Fitted parameters of the RTP decay curves of the F-BNDs and BNDs.

Sample	$\tau_1$ (s)	$\alpha_1$ (%)	$\tau_2$ (s)	$\alpha_2$ (%)	$\tau_{\text{avg}}$ (s)	$\emptyset$
F-BNDs(e)	0.393	15.48	1.222	84.52	1.175	1.210
F-BNDs(p)	0.211	23.69	1.131	73.61	1.074	1.176
F-BNDs(t)	0.055	42.51	0.415	57.49	0.383	1.557
BNDs(e)	0.051	1.67	0.896	98.33	0.895	1.134
BNDs(p)	0.148	29.25	0.553	70.75	0.513	1.169
BNDs(t)	0.021	63.50	0.129	36.50	0.106	1.325

**Tab. S2** Phosphorescence lifetime comparison of some reported CD-based materials and F-BNDs.

Samples	Room-temperature Lifetime (ms)	High-temperature Lifetime (ms)	Ref.
B-CDs@PAM	637	—	6
M-CDs	243	—	7
FNCDs	1140	—	5
NCDs	1060	—	8
CDs/PVP	476	—	9
CNDs	193	—	10
MP-CDs	880	—	11
FP-CDs	175	—	12
CD@PVA	292	—	13
CNDs	1387	—	14
FCNDs	1210	—	15
<b>F-BNDs(e)</b>	<b>1175</b>	<b>250 (150 °C)</b>	<b>This work</b>

**Tab. S3** The -NH<sub>2</sub> and -OH groups ratios of F-BNDs(e), F-BNDs(p) and F-BNDs(t) in N1s and O1s spectra.

Samples	-NH <sub>2</sub> (%)	-OH (%)
F-BNDs(e)	36.71	56.35
F-BNDs(p)	27.29	44.18
F-BNDs(t)	15.94	43.52



## **Supplementary video S1**

The video S1 demonstrates that the F-BNDs(e) powder could emit green room temperature phosphorescence after the stoppage of 405 nm excitation, lasting over 10 s by the naked eyes.

## References

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